



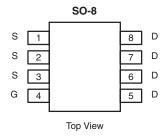
N-Channel Reduced Q_g , Fast Switching MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
30	0.0085 at V _{GS} = 10 V	± 13		
	0.014 at V _{GS} = 4.5 V	± 10		

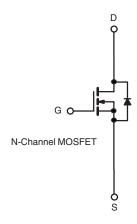
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFETS
- High-Efficiency
- **PWM Optimized**
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si4880DY-T1-E3 (Lead (Pb)-free)
Si4880DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 25		
Continuous Drain Current (T,I = 150 °C) ^{a, b}	T _A = 25 °C	1-	± 13		
Continuous Drain Current (1 _J = 150 °C) ⁻⁵	T _A = 70 °C	I _D	± 10	^	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	± 50	A	
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	2.3		
a h	T _A = 25 °C	P _D	2.5	w	
Maximum Power Dissipation ^{a, b}	T _A = 70 °C		1.6	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient (MOSFET) ^a	t ≤ 10 s	R_{thJA}		50	°C/W
	Steady State		70] C/VV

a. Surface mounted on FR4 board.

b. $t \le 10 \text{ s}$.

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MOSFET SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions			Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.8		1.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zoro Coto Voltogo Droin Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	1		1		
Zero Gate Voltage Drain Current		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
Durin Course On Olada Basistana d	R _{DS(on)}	V _{GS} = 10 V, I _D = 13 A		0.0069	0.0085	0	
Drain-Source On-State Resistance ^a		V _{GS} = 4.5 V, I _D = 10 A		0.0115	0.014	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 13 A		26		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.3, V _{GS} = 0 V		0.70	1.1	V	
Dynamic ^b							
Total Gate Charge	Qg			19.5	25		
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 5.0 \text{ V}, I_{D} = 13 \text{ A}$		4.2		nC	
Gate-Drain Charge	Q _{gd}			8.8			
Turn-On Delay Time	t _{d(on)}			14	22		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω $I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		9	15	ns	
Turn-Off DelayTime	t _{d(off)}			46	70		
Fall Time	t _f			30	45		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.3 A, dl/dt = 100 A/μs		35	70		

Notes:

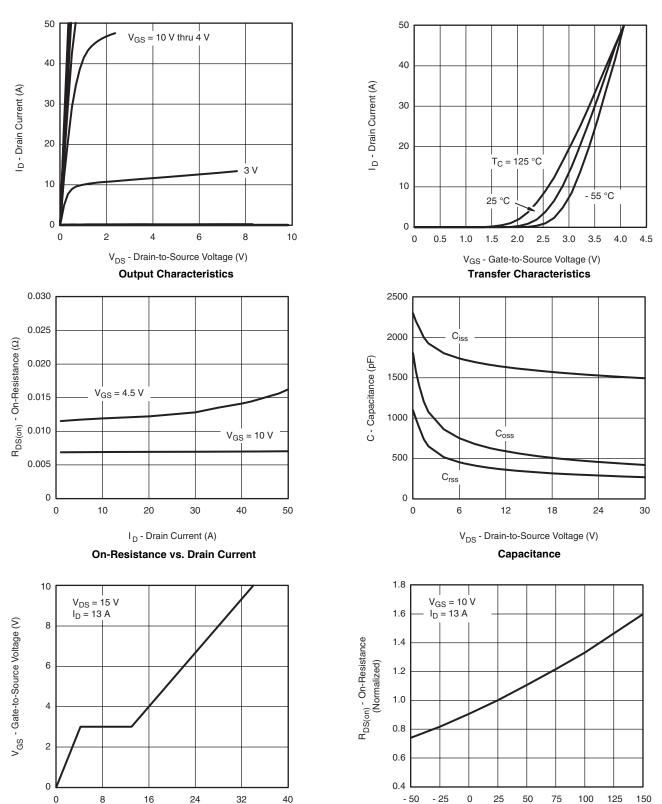
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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Q_g - Total Gate Charge (nC)

Gate Charge

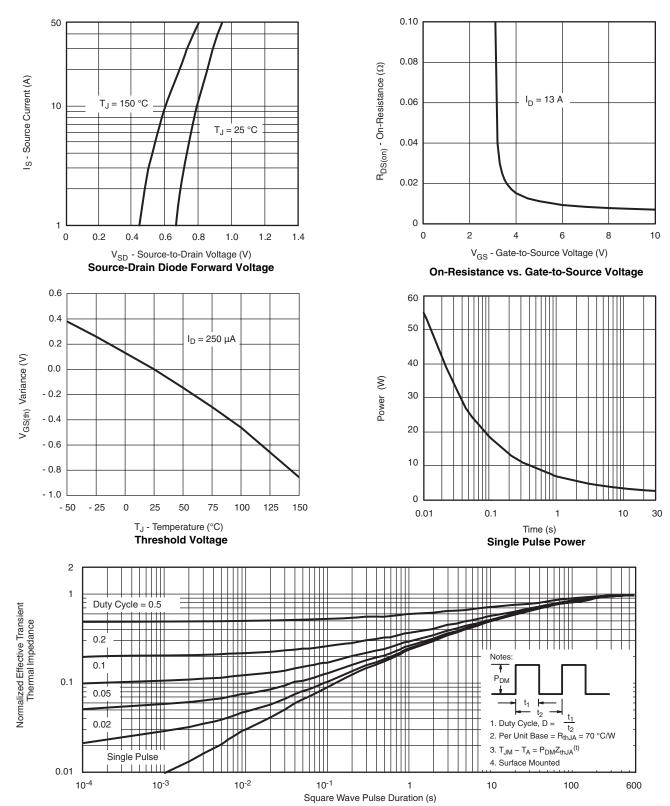
T_J - Junction Temperature (°C)

On-Resistance vs. Junction Temperature

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

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